## NSN 5961-01-276-4709

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## Inclosure Material:

Plastic

**Overall Length:** 

0.190 inches

## Terminal Length:

0.500 inches

## **Overall Height:**

0.670 inches

**Overall Width:** 

0.145 inches

## **Function For Which Designed:**

Amplifier and general purpose

## Internal Configuration:

## Junction contact

## Joint Electronic Device Engineering Council/jedec/case Outline Designation:

# То-92

Mounting Method:

Terminal

## Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

40.0 collector to emitter voltage/static/base open and 30.0 collector to base voltage/static/emitter open and 4.0 emitter to base voltage, static, collector open

## **Current Rating Per Characteristic:**

1.00 amperes source cutoff current

## **Power Rating Per Characteristic:**

1.5 watts small-signal input power, common-collector absolute

## Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

## **Special Features:**

Junction pattern arrangement: pnp

## **Terminal Type And Quantity:**

3 uninsulated wire lead

#### Shelf Life:

N/a

## Unit Of Measure:

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## Demilitarization:

No

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